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1N4454



High Conductance Ultra Fast Diode

Sourced from Process 1R. See MMBD1201-1205 for characteristics.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
W _{IV}	Working Inverse Voltage	50	V
Io	Average Rectified Current	200	mA
I _F	DC Forward Current	400	mA
İf	Recurrent Peak Forward Current	600	mA
İ _f (surge)	Peak Forward Surge Current Pulse width = 1.0 second Pulse width = 1.0 microsecond	1.0 4.0	A A
T _{stg}	Storage Temperature Range	-65 to +200	°C
TJ	Operating Junction Temperature	175	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 200 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		1N4454	
P_{D}	Total Device Dissipation	500	mW
	Derate above 25°C	3.33	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	300	°C/W

High Conductance Ultra Fast Diode (continued)

Electrical Characteristics

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
B _V	Breakdown Voltage	$I_R = 5.0 \mu\text{A}$	75		V
I _R	Reverse Current	$V_R = 50 \text{ V}$ $V_R = 50 \text{ V}, T_A = 150^{\circ}\text{C}$		100 100	nA μA
V _F	Forward Voltage	$I_F = 250 \mu A$ $I_F = 1.0 mA$ $I_F = 2.0 mA$ $I_F = 10 mA$	505 550 610	575 650 710 1.0	mV mV mV
Co	Diode Capacitance	$V_R = 0$, $f = 1.0 \text{ MHz}$		4.0	pF
T _{RR}	Reverse Recovery Time	$I_F = 10 \text{ mA}, V_R = 1.0 \text{ V},$ $I_{rr} = 1.0 \text{ mA}, R_L = 100 \Omega$		4.0	nS

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